

EGP30A - EGP30K

Features

- Glass passivated cavity-free junction.
- High surge current capability.
- Low leakage current.
- Superfast recovery time for high efficiency.
- Low forward voltage, high current capability.



DO-201AD COLOR BAND DENOTES CATHODE

Fast Rectifiers (Glass Passivated)

Absolute Maximum Ratings* T_A = 25°C unless otherwise noted

Symbol	Parameter	Value								Units
		30A	30B	30C	30D	30F	30G	30J	320	1
V_R	Breakdown Voltage		100	150	200	300	400	600	800	V
I _{F(AV)}	Average Rectified Forward Current, .375 " lead length @ $T_A = 55$ °C 3.0				А					
I _{FSM}	Non-repetitive Peak Forward Surge Current 8.3 ms Single Half-Sine-Wave		125							Α
T _{stg}	Storage Temperature Range		-65 to +150							°C
T_J	Operating Junction Temperature		-65 to +150							°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics

Symbol	Parameter	Value	Units
P _D	Power Dissipation	6.25	W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	20	°C/W
$R_{\theta JL}$	Thermal Resistance, Junction to Lead	8.5	°C/W

Electrical Characteristics T_A = 25°C unless otherwise noted

Symbol	Parameter	Device							Units	
			30B	30C	30D	30F	30G	30J	320	
V _F	Forward Voltage @ 3.0 A		0.95				1.25		.7	V
t _{rr}	Reverse Recovery Time $I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$		50						'5	ns
I _R	Reverse Current @ rated V_R $T_A = 25^{\circ}C$ $T_A = 125^{\circ}C$		5.0 100							μA μA
C_T	Total Capacitance $V_R = 4.0 \text{ V}, f = 1.0 \text{ MHz}$		95				75			pF

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Typical Characteristics

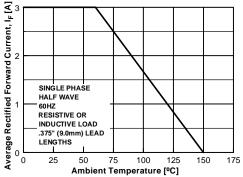


Figure 1. Forward Current Derating Curve

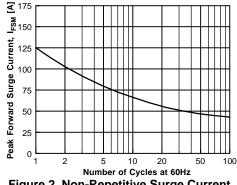


Figure 2. Non-Repetitive Surge Current

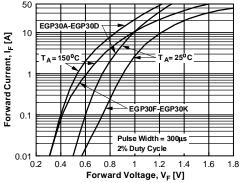


Figure 3. Forward Voltage Characteristics

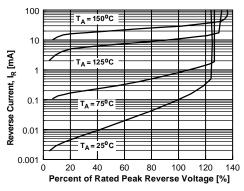


Figure 4. Reverse Current vs Reverse Voltage

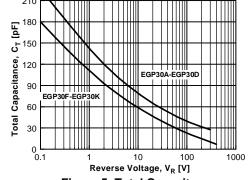
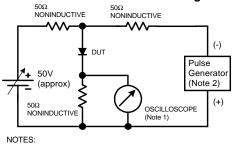


Figure 5. Total Capacitance



1. Rise time = 7.0 ns max; Input impedance = 1.0 megaohm 22 pf. 2. Rise time = 10 ns max; Source impedance = 50 ohms.

+0.5A 0 -0.25A -1.0A

Reverse Recovery Time Characterstic and Test Circuit Diagram

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